



Docket No.: 244748US2S DIV

COMMISSIONER FOR PATENTS  
ALEXANDRIA, VIRGINIA 22313

RE: Application Serial No.: 10/714,916

Applicants: Wataru SAITO, et al.

Filing Date: November 18, 2003

For: POWER SEMICONDUCTOR DEVICE HAVING  
RESURF LAYER

Group Art Unit:

Examiner:

SIR:

Attached hereto for filing are the following papers:

**Supplemental Preliminary Amendment**

Our check in the amount of **\$0.00** is attached covering any required fees. In the event any variance exists between the amount enclosed and the Patent Office charges for filing the above-noted documents, including any fees required under 37 C.F.R. 1.136 for any necessary Extension of Time to make the filing of the attached documents timely, please charge or credit the difference to our Deposit Account No. 15-0030. Further, if these papers are not considered timely filed, then a petition is hereby made under 37 C.F.R. 1.136 for the necessary extension of time. A duplicate copy of this sheet is enclosed.

Respectfully submitted,

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DOCKET NO: 244748US2S DIV

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF

WATARU SAITO, ET AL.

: EXAMINER:

SERIAL NO: 10/714,916

:

FILED: NOVEMBER 18, 2003

: GROUP ART UNIT:

FOR: POWER SEMICONDUCTOR  
DEVICE HAVING RESURF LAYER

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SUPPLEMENTAL PRELIMINARY AMENDMENT

COMMISSIONER FOR PATENTS  
ALEXANDRIA, VIRGINIA 22313

SIR:

Supplemental to the preliminary amendment filed November 18, 2003, please amend the above-identified application as follows:

**Amendments to the Specification** begin on page 2 of this paper.

**Remarks/Arguments** begin on page 4 of this paper.